

View Online at <https://aerobasegroup.com/nsn/5961-00-710-9389>

Inclosure Material:

Metal

Overall Length:

0.259 inches

Terminal Length:

0.750 inches

Overall Diameter:

0.362 inches

Component Name And Quantity:

1 semiconductor device diode and 1 transistor

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Semiconductor Material:

Silicon single transistor

Voltage Rating In Volts Per Characteristic:

45.0 collector to emitter voltage/static/base open single transistor

Current Rating Per Characteristic:

6.00 milliamperes source cutoff current horsepower metric single semiconductor device diode

Power Rating Per Characteristic:

250.0 milliwatts small-signal input power, common-collector absolute single transistor

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

4 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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